FN2897.5

## Data Sheet

# Features

• Very High Slew Rate 400V/µs
• Fast Settling Time140ns
- Wide Gain Bandwidth (A_V $\geq$ 10) 400MHz
• Power Bandwidth
Low Offset Voltage
Input Voltage Noise 6nV/\/Hz
Output Voltage Swing ±10V

Monolithic Bipolar Construction

July 2003

## Applications

- Pulse and Video Amplifiers
- Wideband Amplifiers
- High Speed Sample-Hold Circuits
- Fast, Precise D/A Converters

# **Ordering Information**

PART NUMBER	TEMP. RANGE ( <sup>o</sup> C)	PACKAGE	PKG. DWG. #
HA1-2540-5	0 to 75	14 Ld CERDIP	F14.3

# 400MHz, Fast Settling Operational Amplifier

The Intersil HA-2540 is a wideband, very high slew rate, monolithic operational amplifier featuring superior speed and bandwidth characteristics. Bipolar construction coupled with dielectric isolation allows this truly differential device to deliver outstanding performance in circuits where closed loop gain is 10 or greater. Additionally, the HA-2540 has a drive capability of  $\pm 10V$  into a  $1k\Omega$  load. Other desirable characteristics include low input voltage noise, low offset voltage, and fast settling time.

A 400V/ $\mu$ s slew rate ensures high performance in video and pulse amplification circuits, while the 400MHz gainbandwidth product is ideally suited for wideband signal amplification. A settling time of 140ns also makes the HA-2540 an excellent selection for high speed Data Acquisition Systems.

Refer to Application Note AN541 and Application Note AN556 for more information on High Speed Op Amp applications.

For a lower power version of this product, please see the HA-2850 datasheet.

# Pinout





### **Absolute Maximum Ratings**

### **Operating Conditions**

Temperature Range

### **Thermal Information**

Thermal Resistance (Typical, Note 2)	θ <sub>JA</sub> ( <sup>o</sup> C/W)	θ <sub>JC</sub> ( <sup>o</sup> C/W)
CERDIP Package	75	20
Maximum Internal Power Dissipation (Not	e 1)	
Maximum Junction Temperature (Ceramic	c Package)	175 <sup>0</sup> C
Maximum Storage Temperature Range .	65	5°C to 150°C
Maximum Lead Temperature (Soldering 1	0s)	300 <sup>0</sup> C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTES:

 Maximum power dissipation with load conditions must be designed to maintain the maximum junction temperature below 175<sup>o</sup>C for the ceramic package, and below 150<sup>o</sup>C for the plastic package. By using Application Note AN556 on Safe Operating Area Equations, along with the thermal resistances, proper load conditions can be determined. Heat sinking is recommended above 75<sup>o</sup>C.

2.  $\theta_{\text{JA}}$  is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications	$V_{SUPPLY} = \pm 15V, R_L = 1k\Omega, C_H$	L < 10pF, Unless Otherwise Specified
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PARAMETER	TEMP ( <sup>o</sup> C)	MIN	ТҮР	MAX	UNITS	
INPUT CHARACTERISTICS						
Offset Voltage	25	-	8	15	mV	
	Full	-	13	20	mV	
Average Offset Voltage Drift	Full	-	20	-	μV/ <sup>o</sup> C	
Bias Current	25	-	5	20	μA	
	Full	-	-	25	μA	
Offset Current	25	-	1	6	μA	
	Full	-	-	8	μA	
Input Resistance	25	-	10	-	kΩ	
Input Capacitance	25	-	1	-	pF	
Common Mode Range	Full	±10	-	-	V	
Input Noise Current (f = 1kHz, R <sub>SOURCE</sub> = 0Ω)	25	-	6	-	pA/√Hz	
Input Noise Voltage (f = 1kHz, $R_{SOURCE} = 0\Omega$ )	25	-	6	-	nV/√Hz	
TRANSFER CHARACTERISTICS			1		1	
Large Signal Voltage Gain (Note 3)	25	10	15	-	kV/V	
	Full	5	-	-	kV/V	
Common-Mode Rejection Ratio (Note 4)	Full	60	72	-	dB	
Minimum Stable Gain	25	10	-	-	V/V	
Gain Bandwidth Product (Notes 5, 6)	25	-	400	-	MHz	
OUTPUT CHARACTERISTICS			1		1	
Output Voltage Swing (Notes 3, 10)	Full	±10	-	-	V	
Output Current (Note 3)	25	±10	±20	-	mA	
Output Resistance	25	-	30	-	Ω	
Full Power Bandwidth (Notes 3, 7)	25	5.5	6	-	MHz	
TRANSIENT RESPONSE (Note 8)			1		1	
Rise Time	25	-	14	-	ns	
Overshoot	25	-	5	-	%	
Slew Rate	25	320	400	-	V/µs	
Settling Time: 10V Step to 0.1%	25	-	140	-	ns	

**Electrical Specifications**  $V_{SUPPLY} = \pm 15V$ ,  $R_L = 1k\Omega$ ,  $C_L < 10pF$ , Unless Otherwise Specified (Continued)

PARAMETER	TEMP ( <sup>o</sup> C)	MIN	TYP	MAX	UNITS
POWER REQUIREMENTS					
Supply Current	Full	-	20	25	mA
Power Supply Rejection Ratio (Note 9)	Full	60	70	-	dB

NOTES:

3.  $R_L$  = 1kΩ,  $V_O$  = ±10V.

4.  $V_{CM} = \pm 10V.$ 

5.  $V_0 = 90 \text{mV}.$ 

6.  $A_V = 10$ . 7. Full power bandwidth guaranteed based on slew rate measurement using: FPBW =  $\frac{\text{Slew Rate}}{2\pi V_{\text{PEAK}}}$ 

8. Refer to Test Circuits section of the data sheet.

9. V<sub>SUPPLY</sub> = +5V, -15V and +15V, -5V.

10. Guaranteed range for output voltage is ±10V. Functional operation outside of this range is not guaranteed.

# Test Circuits and Waveforms







Vertical Scale: A = 0.5V/Div., B = 5.0V/Div. Horizontal Scale: 50ns/Div.

#### LARGE SIGNAL RESPONSE



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Vertical Scale: Input = 10mV/Div.; Output = 50mV/Div. Horizontal Scale: 20ns/Div.

#### SMALL SIGNAL RESPONSE

#### NOTES:

13.  $A_V = -10$ .

- 14. Load Capacitance should be less than 10pF. Turn on time delay typically 4ns.
- 15. It is recommended that resistors be carbon composition and the feedback and summing network ratios be matched to 0.1%.
- 16. SETTLE POINT (Summing Node) capacitance should be less than 10pF. For optimum settling time results, it is recommended that the test circuit be constructed directly onto the device pins. A Tektronix 568 Sampling Oscilloscope with S-3A sampling heads is recommended as a settle point monitor.

#### FIGURE 2. SETTLING TIME TEST CIRCUIT



# **Typical Applications**



NOTE: With one HA-2540 and two low capacitance switching diodes, signals exceeding 10MHz can be separated. This circuit is most useful for full wave rectification, AM detectors or sync generation.

### FIGURE 3. WIDEBAND SIGNAL SPLITTER



- 17. Used for experimental purposes.  $C_{F}\cong 3pF.$
- 18. C<sub>1</sub> is optional (0.001 $\mu$ F  $\rightarrow$  0.01 $\mu$ F ceramic).
- 19.  $R_5$  is optional and can be utilized to reduce input signal amplitude and/or balance input conditions.  $R_5 = 500\Omega$  to 1k $\Omega$ .

#### FIGURE 4. BOOTSTRAPPING FOR MORE OUTPUT CURRENT AND VOLTAGE SWING

Refer to Application Note AN541 For Further Application Information.



# Typical Performance Curves

# Typical Performance Curves (Continued)







Vertical Scale: 10mV/Div. Horizontal Scale: 50ms/Div.

FIGURE 13. BROADBAND NOISE (0.1Hz TO 1MHz)



FIGURE 15. POWER SUPPLY REJECTION RATIO vs FREQUENCY

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FIGURE 12. INPUT NOISE VOLTAGE AND NOISE CURRENT vs FREQUENCY



FIGURE 14. COMMON MODE REJECTION RATIO vs FREQUENCY



# **Die Characteristics**

# DIE DIMENSIONS:

62 mils x 76 mils x 19 mils 1575 μmx 1930μm x 483μm

# METALLIZATION:

Type: Al, 1% Cu Thickness: 16kÅ ±2kÅ

# PASSIVATION:

Type: Nitride (Si $_3N_4$ ) over Silox (SiO $_2$ , 5% Phos.) Silox Thickness: 12kÅ ±2kÅ Nitride Thickness: 3.5kÅ ±1.5kÅ

# Metallization Mask Layout

### SUBSTRATE POTENTIAL (Powered Up):

V-

### TRANSISTOR COUNT:

30

### PROCESS:

**Bipolar Dielectric Isolation** 

HA-2540



+ IN

- IN

# Ceramic Dual-In-Line Frit Seal Packages (CERDIP)



NOTES:

- 1. Index area: A notch or a pin one identification mark shall be located adjacent to pin one and shall be located within the shaded area shown. The manufacturer's identification shall not be used as a pin one identification mark.
- 2. The maximum limits of lead dimensions b and c or M shall be measured at the centroid of the finished lead surfaces, when solder dip or tin plate lead finish is applied.
- 3. Dimensions b1 and c1 apply to lead base metal only. Dimension M applies to lead plating and finish thickness.
- 4. Corner leads (1, N, N/2, and N/2+1) may be configured with a partial lead paddle. For this configuration dimension b3 replaces dimension b2.
- 5. This dimension allows for off-center lid, meniscus, and glass overrun.
- 6. Dimension Q shall be measured from the seating plane to the base plane.
- 7. Measure dimension S1 at all four corners.
- 8. N is the maximum number of terminal positions.
- 9. Dimensioning and tolerancing per ANSI Y14.5M 1982.
- 10. Controlling dimension: INCH.

F14.3 MIL-STD-1835 GDIP1-T14 (D-1, CONFIGURATION )	A)
14 LEAD CERAMIC DUAL-IN-LINE FRIT SEAL PACKAGE	

	INC	HES	MILLIM		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
A	-	0.200	-	5.08	-
b	0.014	0.026	0.36	0.66	2
b1	0.014	0.023	0.36	0.58	3
b2	0.045	0.065	1.14	1.65	-
b3	0.023	0.045	0.58	1.14	4
с	0.008	0.018	0.20	0.46	2
c1	0.008	0.015	0.20	0.38	3
D	-	0.785	-	19.94	5
E	0.220	0.310	5.59	7.87	5
е	0.100 BSC		2.54 BSC		-
eA	0.300 BSC		7.62 BSC		-
eA/2	0.150	0.150 BSC		3.81 BSC	
L	0.125	0.200	3.18	5.08	-
Q	0.015	0.060	0.38	1.52	6
S1	0.005	-	0.13	-	7
α	90 <sup>0</sup>	105 <sup>0</sup>	90 <sup>0</sup>	105 <sup>0</sup>	-
aaa	-	0.015	-	0.38	-
bbb	-	0.030	-	0.76	-
CCC	-	0.010	-	0.25	-
М	-	0.0015	-	0.038	2, 3
N	14		14		8

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